Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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HAT2172N

Silicon N Channel Power MOS FET Power Switching

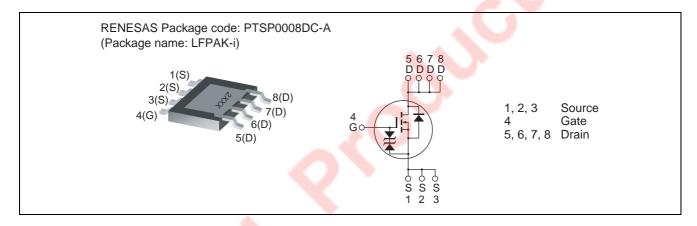
REJ03G1683-0100 Rev.1.00 May 28, 2008

Features

- High speed switching
- Capable of 7 V gate drive
- Low drive current
- High density mounting
- Low on-resistance

 $R_{DS(on)}\!=6.1~\text{m}\Omega$ typ. (at $V_{GS}\!=10~\text{V})$

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	40	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	I _D	30	А
Drain peak current	I _{D(pulse)} Note1	120	А
Body-drain diode reverse drain current	I _{DR}	30	А
Avalanche current	I _{AP} Note 2	20	А
Avalanche energy	E _{AR} Note 2	20	mJ
Channel dissipation	Pch Note3	20	W
Channel to case thermal resistance	θch-C	6.25	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tch = 25°C, Rg \geq 50 Ω

3. $Tc = 25^{\circ}C$

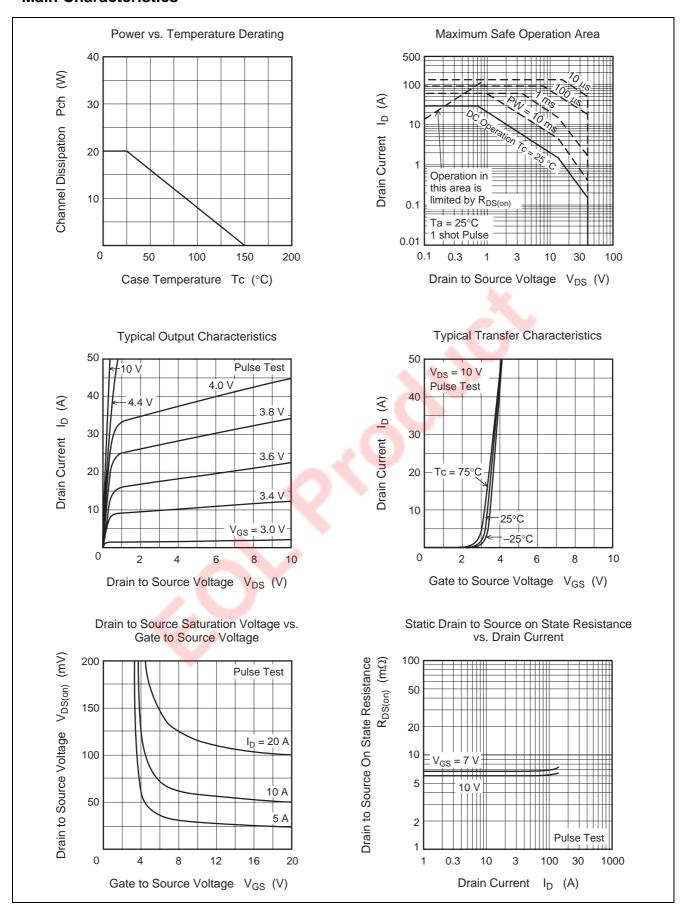
Electrical Characteristics

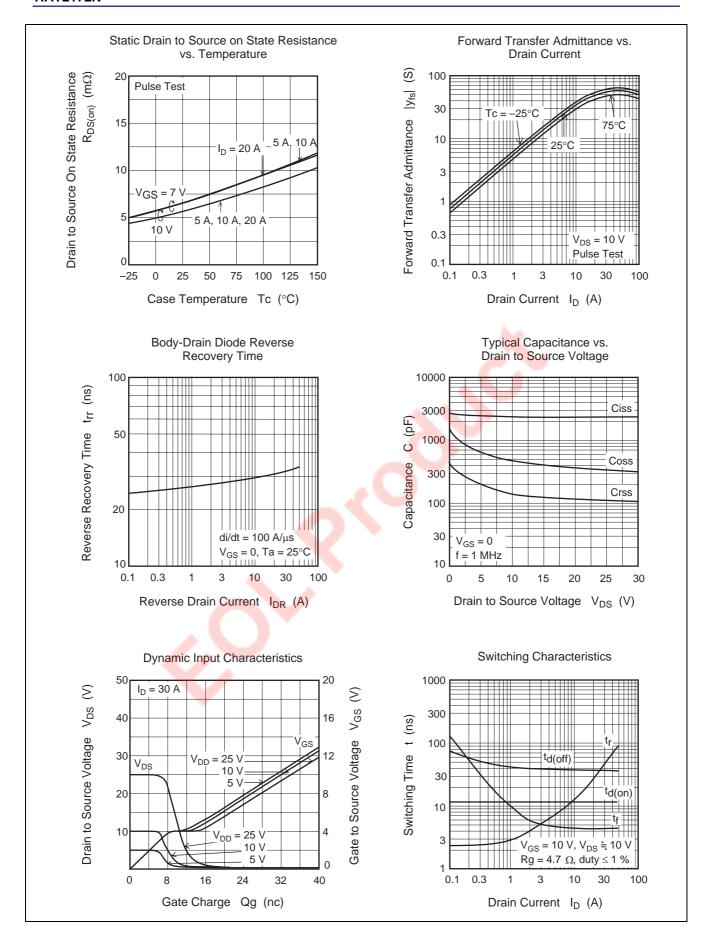
 $(Ta = 25^{\circ}C)$

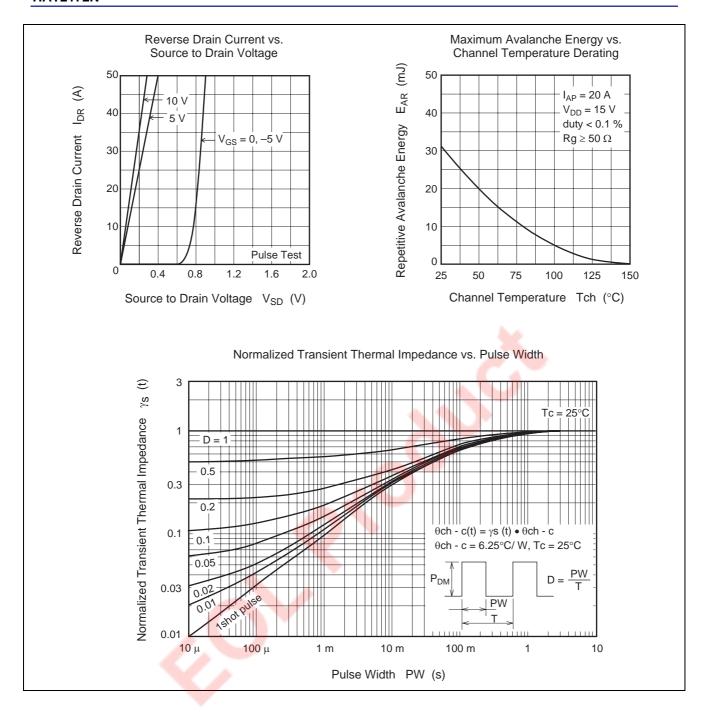
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	40	—	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	_		V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 40 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.5	_	3.0	V	$V_{DS} = 10 \text{ V}, I_{D} = 10 \text{mA}$
Static drain to source on state	R _{DS(on)}	_	6.1	7.8	$m\Omega$	$I_D = 15 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
resistance	R _{DS(on)}	_	6.9	9.5	$m\Omega$	$I_D = 15 \text{ A}, V_{GS} = 7 \text{ V}^{\text{Note4}}$
Forward transfer admittance	y _{fs}	27	45		S	$I_D = 15 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss	_	2420	_	pF	$V_{DS} = 10 \ V, V_{GS} = 0,$
Output capacitance	Coss	_	480	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	_	150		pF	
Gate resistance	Rg	_	0.5		Ω	
Total gate charge	Qg	_	32		nC	$V_{DD} = 10 \text{ V}, V_{GS} = 10 \text{ V},$
Gate to source charge	Qgs	_	9	_	nC	$I_D = 30 \text{ A}$
Gate to drain charge	Qgd	_	4.0	_	nC	
Turn-on delay time	t _{d(on)}	_	12	_	ns	$V_{GS} = 10 \text{ V}, I_D = 15 \text{ A},$
Rise time	t _r	_	20		ns	$V_{DD} \cong 10 \text{ V}, R_L = 0.67 \Omega,$
Turn-off delay time	t _{d(off)}	_	38	_	ns	$Rg = 4.7 \Omega$
Fall time	t _f	_	4.5		ns	
Body-drain diode forward voltage	V_{DF}		0.84	1.10	V	$I_F = 30 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery	t _{rr}	_	32	Ĺ	ns	$I_F = 30 \text{ A}, V_{GS} = 0$
time						$di_F/dt = 100 \text{ A}/ \mu\text{s}$

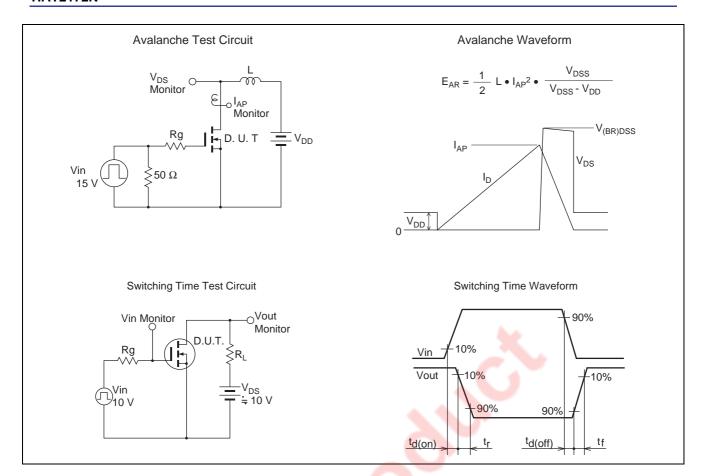
Notes: 4. Pulse test

Main Characteristics

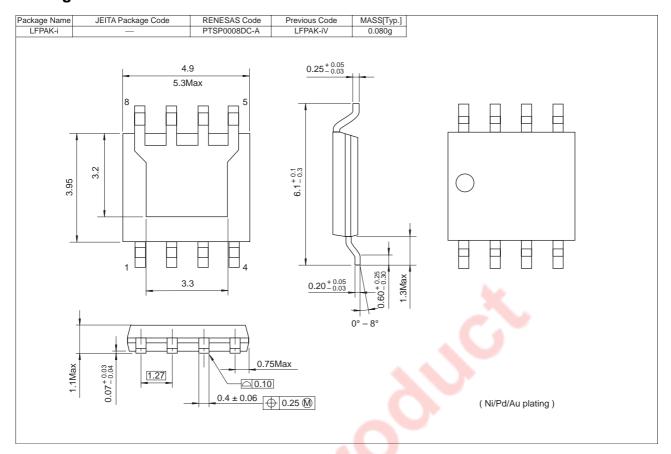








Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
HAT2172N-EL-E	2500 pcs	Taping

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